INTEGRATED CIRCUITS

DATA SHEET

CBT3251
1-of-8 FET multiplexer/demultiplexer

Preliminary data 2002 Sep 09





1-of-8 FET multiplexer/demultiplexer

CBT3251

FEATURES

- 5 Ω switch connection between two ports
- TTL-compatible input levels
- Minimal propagation delay through the switch
- ESD protection exceeds 2000 V HBM per JESD22-A114,
 200 V MM per JESD22-A115 and 1000 V CDM per JESD22-C101
- Latch-up testing is done to JESDEC Standard JESD78 which exceeds 100 mA

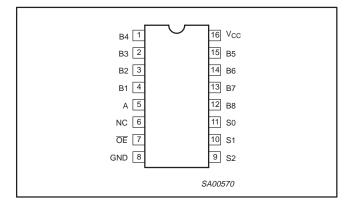
DESCRIPTION

The CBT3251 is a 1-of-8 high-speed TTL-compatible FET multiplexer/demultiplexer. The low on resistance of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise.

When output enable (\overline{OE}) is low, the CBT3251 is enabled. S0, S1, and S2 select one of the B outputs for the A-input data.

The CBT3251 is characterized for operation from -40 to +85°C.

PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 2, 3, 4, 12, 13, 14, 15	B1, B2, B3, B4, B5, B6, B7, B8	B outputs
5	А	A input
6	NC	No internal connection
7	ŌĒ	Output enable
8	GND	Ground (0 V)
9, 10, 11	S0, S1, S2	Select-control input
16	V _{CC}	Positive supply voltage

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	TOPSIDE MARK	DWG NUMBER
16-pin plastic SOIC	−40 to 85 °C	CBT3251D	CBT3251D	SOT109-1
16-pin plastic SSOP	−40 to 85 °C	CBT3251DB	CT3251	SOT338-1
16-pin plastic SSOP (QSOP)	−40 to 85 °C	CBT3251DS	CBT3251	SOT519-1
16-pin plastic TSSOP	−40 to 85 °C	CBT3251PW	CBT3251	SOT403-1

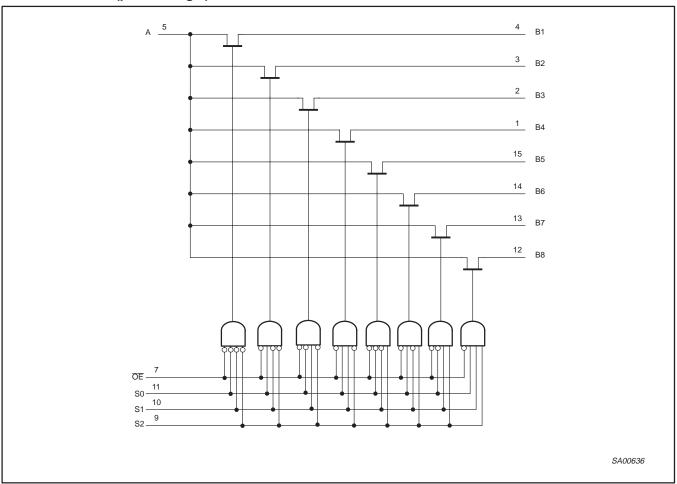
Standard packing quantities and other packaging data is available at www.philipslogic.com/packaging.

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LOGIC DIAGRAM (positive logic)



FUNCTION TABLE

	INP	UTS		FUNCTION				
OE	S2	S1	S0	FUNCTION				
L	L	L	L	A port = B1 port				
L	L	L	Н	A port = B2 port				
L	L	Н	L	A port = B3 port				
L	L	Н	Н	A port = B4 port				
L	Н	L	L	A port = B5 port				
L	Н	L	Н	A port = B6 port				
L	Н	Н	L	A port = B7 port				
L	Н	Н	Н	A port = B8 port				
Н	Х	Х	Х	Disconnect				

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ABSOLUTE MAXIMUM RATINGS¹

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
VI	DC input voltage ²		-0.5 to +7.0	V
	Continuous channel current		128	mA
I _K	Input clamp current	V _{I/O} < 0	-50	mA
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT		
STWIBUL	PARAMETER	MIN	MAX	ONII	
V _{CC}	DC supply voltage	4.5	5.5	V	
V _{IH}	High-level input voltage	2.0	_	V	
V _{IL}	Low-level Input voltage	_	0.8	V	
T _{amb}	Operating free-air temperature range	-40	+85	°C	

NOTE:

DC ELECTRICAL CHARACTERISTICS

					LIMITS		
SYMBOL	PARAMETER		TEST CONDITIONS	T _{amb}	UNIT		
				MIN	TYP ¹	MAX	1
V_{IK}	Input clamp voltage		$V_{CC} = 4.5 \text{ V}; I_I = -18 \text{ mA}$	_	_	-1.2	V
V_{P}	Pass voltage		$V_I = V_{CC} = 5.5 \text{ V}; I/O = -100 \text{ mA}$	3.4	3.6	3.9	V
I _I	Input leakage current		$V_{CC} = 5.5 \text{ V}; V_I = \text{GND or } 5.5 \text{ V}$	_	_	±1	μΑ
I _{CC}	Quiescent supply current		$V_{CC} = 5.5 \text{ V}; I_{O} = 0, V_{I} = V_{CC} \text{ or GND}$	_	_	3	μΑ
ΔI_{CC}	Control inputs ²		V_{CC} = 5.5 V, one input at 3.4 V, other inputs at V_{CC} or GND	_	_	2.5	mA
C _I	Control pins		V _I = 3 V or 0	_	3.5	_	pF
C	Dower off lookage current	A port	$V_O = 3 \text{ V or } 0; \overline{OE} = V_{CC}$	_	17.5	_	pF
C _{IO(OFF)}	Power-off leakage current	B port	$V_O = 3 \text{ V or } 0; \overline{OE} = V_{CC}$	_	4.0	_	pF
			V _{CC} = 4 V; TYP @ V _{CC} = 4 V; V _I = 2.4 V; I _I = 15 mA	_	14	20	Ω
r_{on}^3	On-resistance		$V_{CC} = 4.5 \text{ V}; V_I = 0 \text{ V}; I_I = 64 \text{ mA}$	_	5	7	Ω
			$V_{CC} = 4.5 \text{ V}; V_I = 0 \text{ V}; I_I = 30 \text{ mA}$		5	7	Ω
			$V_{CC} = 4.5 \text{ V}; V_I = 2.4 \text{ V}; I_I = 15 \text{ mA}$		10	15	Ω

- All typical values are at V_{CC} = 5 V, T_{amb} = 25 °C.
 This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND
 Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

^{1.} Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

^{1.} All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

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AC CHARACTERISTICS

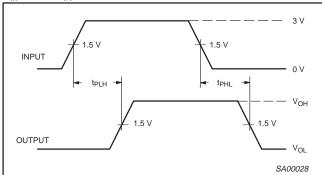
 $T_{amb} = -40 \text{ to } +85 \,^{\circ}\text{C}; \, C_L = 50 \, \text{pF}$

				LIM	ITS	
SYMBOL	PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = +5.0$	UNIT	
			(001101)	MIN	MAX	
t _{pd}	Propagation delay ¹	A or B	B or A		0.25	ns
t _{pd}	Propagation delay	S	А	2	5.5	ns
	Output enable time	S	В	1.5	5.6	ns
t _{en}	to High and Low level	ŌĒ	A or B	1.6	5.8	ns
4	Output disable time	S	В	1.9	6.4	ns
t _{dis}	from High and Low level	ŌĒ	A or B	2.3	6.2	ns

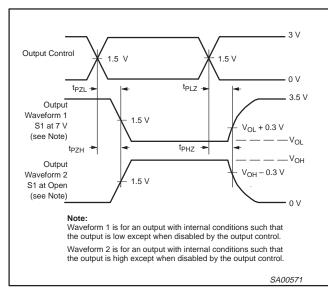
NOTE:

AC WAVEFORMS

 $V_{M} = 1.5V, V_{IN} = GND \text{ to } 3.0V$



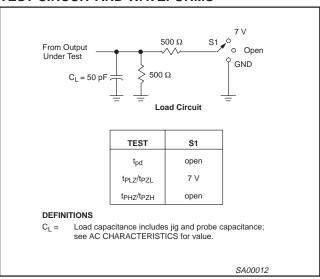
Waveform 1. Input to Output Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times NOTES:

- 1. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- 2. t_{PZL} and t_{PZH} are the same as t_{en}.
- 3. t_{PLH} and t_{PHL} are the same as t_{pd}.

TEST CIRCUIT AND WAVEFORMS



NOTES:

- 1. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O=50~\Omega,~t_f\leq 2.5~ns,~t_f\leq 2.5~ns.$
- The outputs are measured one at a time with one transition per measurement.

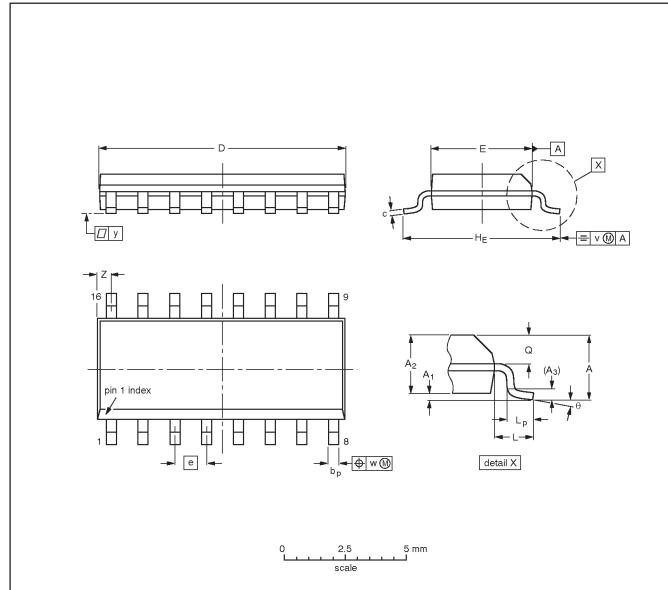
^{1.} The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

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SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				97-05-22 99-12-27	

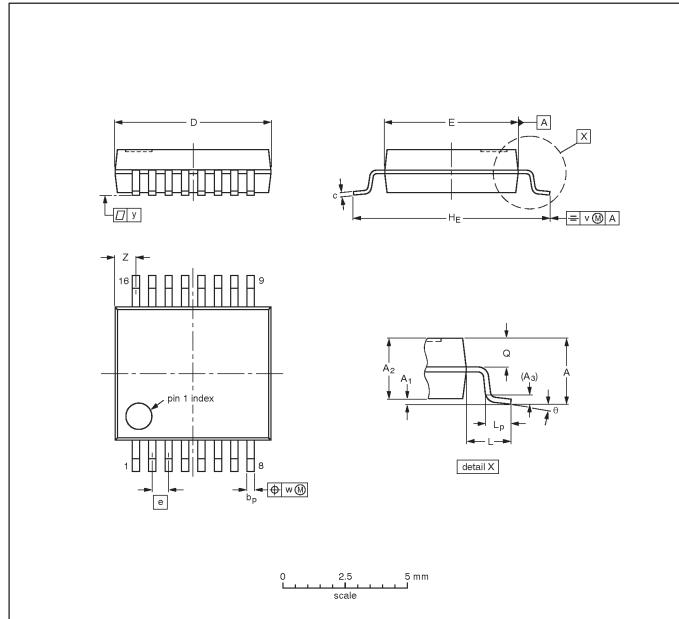
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1-of-8 FET multiplexer/demultiplexer

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SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT338-1		MO-150				-95-02-04 99-12-27

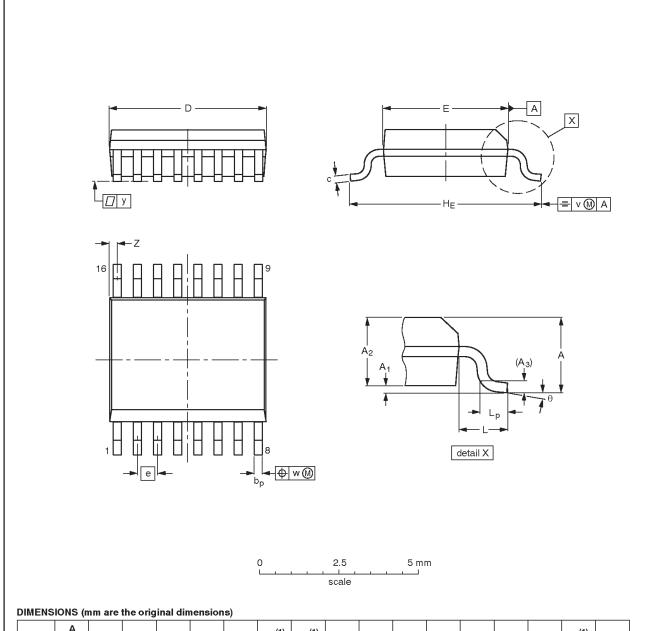
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SSOP16: plastic shrink small outline package; 16 leads; body width 3.9 mm; lead pitch 0.635 mm

SOT519-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	O	D ⁽¹⁾	E ⁽¹⁾	e	HE	L	Lp	٧	w	у	Z ⁽¹⁾	θ
mm	1.73	0.25 0.10	1.55 1.40	0.25	0.31 0.20	0.25 0.18	5.0 4.8	4.0 3.8	0.635	6.2 5.8	1.0	0.89 0.41	0.2	0.18	0.09	0.18 0.05	8° 0°

Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

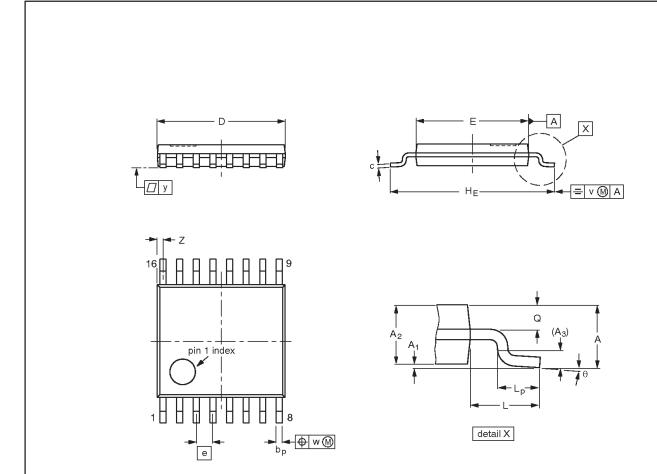
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VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT519-1					99-05-04

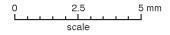
1-of-8 FET multiplexer/demultiplexer

CBT3251

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1





DIMENSIONS (mm are the original dimensions)

UNI	A max.	A ₁	A ₂	A ₃	bр	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT403-1		MO-153				-95-04-04 99-12-27

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Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

^[1] Please consult the most recently issued data sheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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